

10/538923

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PATENT

Docket No.: 4590-421

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of :
Frederic NGUYEN VAN DAU :
U.S. Patent Application No. *not yet assigned* :
Filed: *herewith* :

For: HIGH PERFORMANCE SPIN-VALVE TRANSISTOR

INFORMATION DISCLOSURE STATEMENT

Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Sir:

In accordance with the provisions of 37 C.F.R. 1.56, 1.97 and 1.98, the attention of the Patent and Trademark Office is hereby directed to the documents listed on the attached form PTO-1449. It is respectfully requested that the documents be expressly considered during the prosecution of this application, and that the documents be made of record therein and appear among the "References Cited" on any patent to issue therefrom.

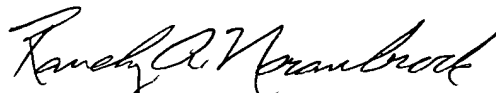
This Information Disclosure Statement is being filed with the application and no certification or fee is required.

This Application is related to U.S. Application Serial No. 10/484,481 filed on July 26, 2002.

Please note this is a PCT application in the entry of the National Phase in the U.S. and copies of the references cited were transmitted by WIPO and are believed to be in the file of the above-identified application and readily available to the Examiner. Therefore it is believed that Applicants have met all requirements regarding duty of disclosure under 37 CFR 1.56. A copy of the foreign search report is attached for the Examiner's information. Acknowledgement and consideration of these documents are respectfully requested.

Respectfully submitted,

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INFORMATION DISCLOSURE CITATION IN AN APPLICATION (PTO-1449)				ATTY. DOCKET NO. 4590-421		U.S. APPLICATION NO. Not yet assigned 38923	
				APPLICANT Frederic NGUYEN VAN DAU			
				FILING DATE herewith		GROUP	
U.S. PATENT DOCUMENTS							
EXAMINER'S INITIALS	PATENT NO.	DATE	NAME	CLASS	SUBCLASS	FILING DATE	
	6, 069,820 A	2000-05-30	Kishi Tatsuya et al				
	2003/214004 A1	2003-11-20	Sato Rie et al				
	2003/122208 A1	2003-07-03	Sato et al				
FOREIGN PATENT DOCUMENTS							
EXAMINER'S INITIALS	PATENT NO.	DATE	COUNTRY	CLASS	SUBCLASS	Translation Yes No	
	2002 305335A	2003-02-05	JP				
	2002 329902 A	2000-11-21	JP				
OTHER ART (Including Author, Title, Date, Pertinent Pages, Etc.)							
	Dijken Van S et al: "Room temperature operation of a high output current magnetic tunnel transistor" Applied physics letters, American Institute of Physics, NY May 6, 2002 pages 3364-3366						
	Monsma D J et al: "Perpendicular Hot Electron Spin-Valve Effect in a New Magnetic Field Sensor: The Spin-Valve Transistor" Physical Review Letters, NY June 26, 1995 pages 5260-5263						
	Kumar P S et al: "The spin-valve transistor" Journal of Physics D (Applied physics) November 21, 2000 IOP Publishing, UK						
	Sato R et al: "Spin-Valve Transistor Formed on Gaas (001) Substrate" IEEE Transactions on Magnetism, IEEE Inc. NY US September 2002 pages 2863-2868						
	M. Guth et al "Tunnel magnetoresistance in magnetic tunnel junctions with a ZnS barrier" Applied Physics Letters May 28, 2001						
	P. Rottlander et al "Tantalum oxide as an alternative low height tunnel barrier in magnetic junctions" Applied Physics Letters May 21, 2001						
EXAMINER				DATE CONSIDERED			

EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; draw line through citation if not in conformance and not considered. Include copy of this form with next communication to Applicant.